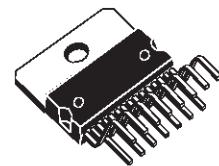


10W+10W+10W/15W TRIPLE AMPLIFIER

PRODUCT PREVIEW

- 10+10W ($R_L = 8\Omega$) + 15W ($R_L = 6\Omega$)
or 10+10+ 10W ($R_L = 8\Omega$)
OUTPUT POWER @ THD = 10% $V_{CC} = 29V$
- INDEPENDENT MUTE FOR CENTER CHANNEL AND MAIN CHANNELS
- NO TURN-ON TURN-OFF POP NOISE
- NO BOUCHEROT CELL
- SINGLE SUPPLY RANGING UP TO 35V
- SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION
- INTERNALLY FIXED GAIN
- SOFT CLIPPING
- MULTIWATT 15 PACKAGE

MULTIPOWER BI50II TECHNOLOGY



Multiwatt15

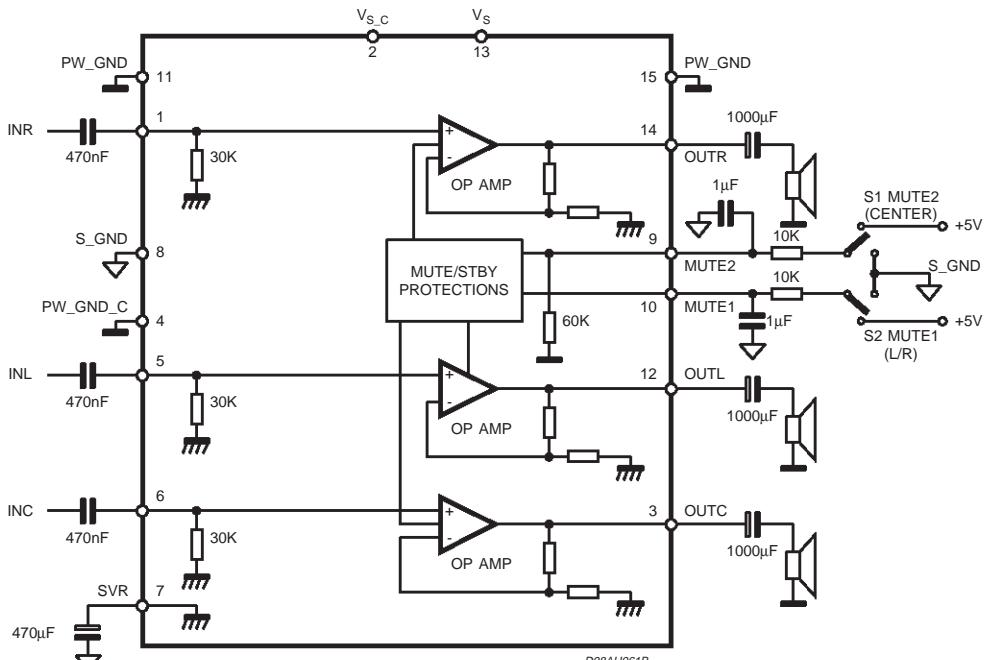
ORDERING NUMBER: TDA7497

DESCRIPTION

The TDA7497 is a triple 10+10+10W/15W class AB power amplifier assembled in the @ Multiwatt 15 package, specially designed for high quality sound, TV applications.

Features of the TDA7497 include mute functions, independently controller for main and center channels.

BLOCK AND APPLICATION DIAGRAM



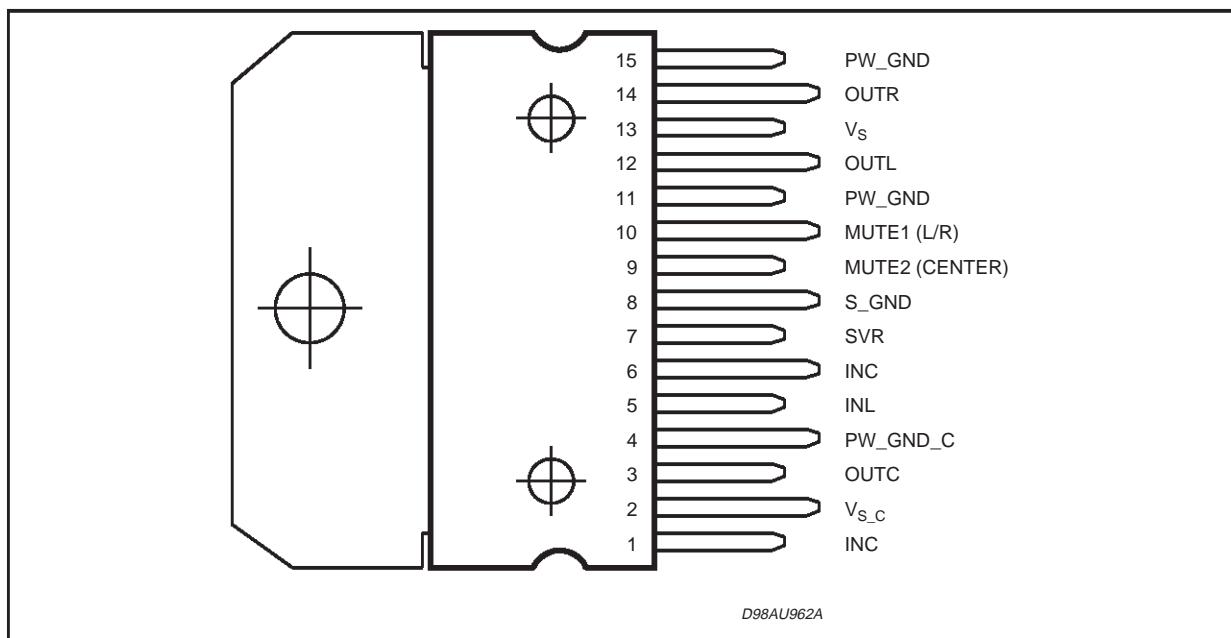
TDA7497

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	DC Supply Voltage	40	V
P_{tot}	Total Power Dissipation ($T_{amb} = 70^\circ\text{C}$)	20	W
T_{amb}	Ambient Operating Temperature (1)	0 to 70	°C
T_{stg}, T_j	Storage and Junction Temperature	-40 to 150	°C

(1) Operation between -20 to 85 °C guaranteed by correlation with 0 to 70°C.

PIN CONNECTION (Top view)



THERMAL DATA

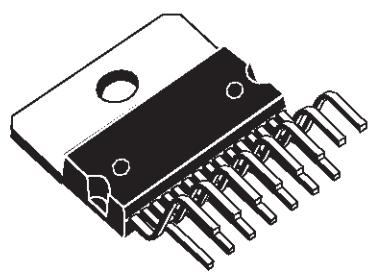
Symbol	Parameter	Value	Unit
$R_{th j-case}$	Thermal Resistance Junction-case	Typ. = 1.3 Max. = 1.9	°C/W
$R_{th j-amb}$	Thermal Resistance Junction-ambient	max	35

ELECTRICAL CHARACTERISTICS (Refer to the test circuit $V_s = 28V$; $R_L = 8\Omega$, $R_g = 50\Omega$, $T_{amb} = 25^\circ C$)

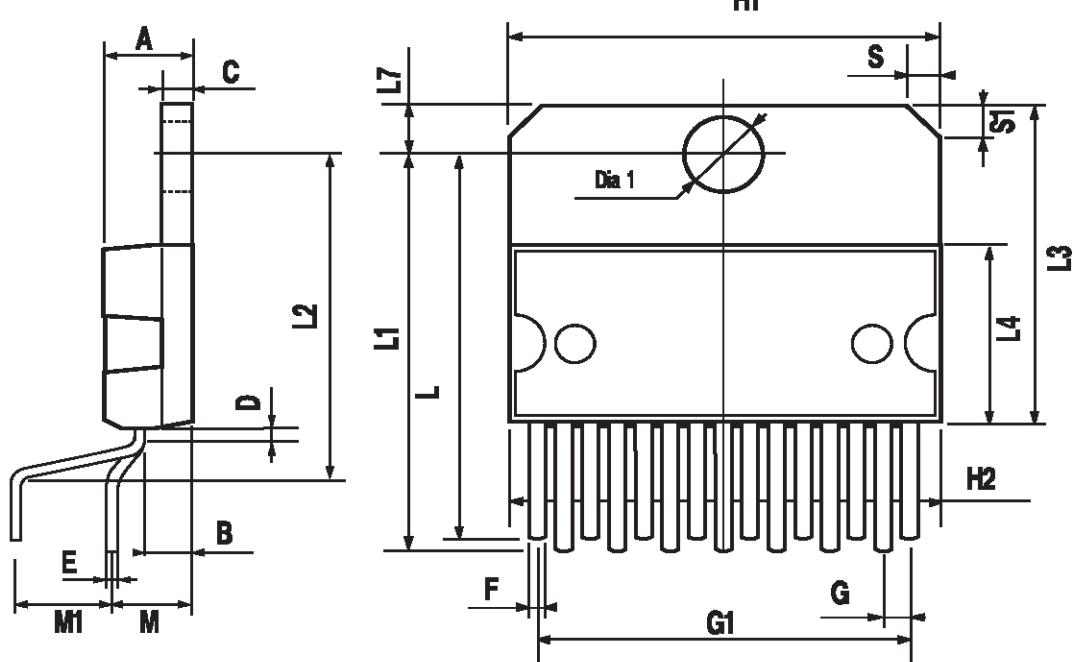
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_s	Supply Voltage Range		11		35	V
I_q	Total Quiescent Current			100		mA
V_o	Quiescent Output Voltage		12.5	14	15.5	V
P_o_{LR}	Output Power Left / Right Channels	THD = 10%; $R_L = 8\Omega$; $V_s = 28V$	10	12		W
		THD = 1%; $R_L = 8\Omega$; $V_s = 28V$	7.8	9.3		W
		THD = 10%; $R_L = 4\Omega$; $V_s = 20V$	7	8		W
		THD = 1%; $R_L = 4\Omega$; $V_s = 20V$	5	6		W
		THD = 10%; $R_L = 8\Omega$; $V_s = 18V$	3.5	3.8		W
		THD = 1%; $R_L = 8\Omega$; $V_s = 18V$	2.2	2.9		W
P_o_c	Output Power Center Channel	THD = 10%; $R_L = 6\Omega$; $V_s = 28V$	15	17		W
		THD = 1%; $R_L = 6\Omega$; $V_s = 28V$	11.7	13.3		W
THD	Total Harmonic Distortion	$P_o = 1W$; $f = 1KHz$;			0.4	%
$I_{peak\ L/R}$	Output Peak Current	(internally limited)	1.7	2.4		A
$I_{peak\ C}$	Output Peak Current Central Channel	(internally limited)	2	2.8		A
G_v	Closed Loop Gain		29	30	31	dB
BW					0.6	MHz
e_N	Total Output Noise	$f = 20Hz$ to $22KHz$		60	150	μV
SR	Slew Rate		5	8		$V/\mu s$
R_i	Input Resistance		22.5	30		$K\Omega$
SVR	Supply Voltage Rejection	$f = 1kHz$ $C_{SVR} = 470\mu F$; $V_{RIP} = 1V_{rms}$	35	39		dB
T_M	Thermal Muting				150	$^\circ C$
T_s	Thermal Shut-down				160	$^\circ C$
MUTE STAND-BY & INPUT SELECTION FUNCTIONS						
V_{MUTE1}	Mute Threshold (L/R)		2.3	2.5	2.7	V
V_{MUTE2}	Mute Threshold (Center only)		2.3	2.5	2.7	V
A_{MUTE}	Mute Attenuation		50	65		dB
$I_{muteBIAS}$	Mute bias current Mute1/Mute2	Mute		1	5	μA
		Play		0.2	2	μA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			5			0.197
B			2.65			0.104
C			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.02	1.27	1.52	0.040	0.050	0.060
G1	17.53	17.78	18.03	0.690	0.700	0.710
H1	19.6			0.772		
H2			20.2			0.795
L	21.9	22.2	22.5	0.862	0.874	0.886
L1	21.7	22.1	22.5	0.854	0.870	0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
M	4.25	4.55	4.85	0.167	0.179	0.191
M1	4.63	5.08	5.53	0.182	0.200	0.218
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152

OUTLINE AND MECHANICAL DATA



Multiwatt15 V



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